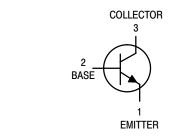
MPS2222A is a Preferred Device

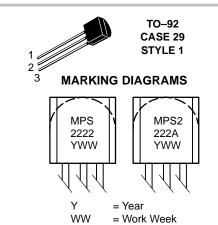
General Purpose Transistors

NPN Silicon



http://onsemi.com





MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|-----------------------------------|----------------|----------------|
| Collector–Emitter Voltage MPS2222 MPS2222A | VCEO | 30 40 | Vdc |
| Collector–Base Voltage MPS2222 MPS2222A | VCBO | 60 75 | Vdc |
| Emitter-Base Voltage MPS2222 MPS2222A | V _{EBO} | 5.0 6.0 | Vdc |
| Collector Current – Continuous | IC | 600 | mAdc |
| Total Device Dissipation @ T _A = 25°C Derate above 25°C | PD | 625 5.0 | mW mW/°C |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | PD | 1.5 12 | Watts mW/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------|------|------|
| Thermal Resistance, Junction to Ambient | $R_{	heta JA}$ | 200 | °C/W |
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 83.3 | °C/W |

ORDERING INFORMATION

| Device | Package | Shipping |
|--------------|---------|------------------|
| MPS2222 | TO-92 | 5000 Units/Box |
| MPS2222A | TO-92 | 5000 Units/Box |
| MPS2222ARLRA | TO-92 | 2000/Tape & Reel |
| MPS2222ARLRM | TO-92 | 2000/Ammo Pack |
| MPS2222ARLRP | TO-92 | 2000/Ammo Pack |
| MPS2222RLRA | TO-92 | 2000/Tape & Reel |
| MPS2222RLRM | TO-92 | 2000/Ammo Pack |
| MPS2222RLRP | TO-92 | 2000/Ammo Pack |

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic | | Symbol | Min | Max | Unit |
|--|--|-----------------------|---|------------------------------|------|
| OFF CHARACTERISTICS | | ' | | • | • |
| Collector–Emitter Breakdown Voltage (I _C = 10 mAdc, I _B = 0) | MPS2222 MPS2222A | V _(BR) CEO | 30 40 | _ _ | Vdc |
| Collector–Base Breakdown Voltage ($I_C = 10 \mu Adc, I_E = 0$) | MPS2222 MPS2222A | V(BR)CBO | 60 75 | _ _ | Vdc |
| Emitter–Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$) | MPS2222 MPS2222A | V _{(BR)EBO} | 5.0 6.0 | _ _ | Vdc |
| Collector Cutoff Current (VCE = 60 Vdc, VEB(off) = 3.0 Vdc) | MPS2222A | ICEX | _ | 10 | nAdc |
| Collector Cutoff Current (V _{CB} = 50 Vdc, I _E = 0) (V _{CB} = 60 Vdc, I _E = 0) (V _{CB} = 50 Vdc, I _E = 0, T _A = 125°C) (V _{CB} = 50 Vdc, I _E = 0, T _A = 125°C) | MPS2222 MPS2222A MPS2222 MPS2222A | ICBO | - - - - | 0.01 0.01 10 10 | μAdc |
| Emitter Cutoff Current (VEB = 3.0 Vdc, I _C = 0) | MPS2222A | IEBO | _ | 100 | nAdc |
| Base Cutoff Current (V _{CE} = 60 Vdc, V _{EB(off)} = 3.0 Vdc) | MPS2222A | I _{BL} | - | 20 | nAdc |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain $ \begin{aligned} &(I_{C} = 0.1 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_{C} = 1.0 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_{C} = 10 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_{C} = 10 \text{ mAdc, } V_{CE} = 10 \text{ Vdc, } T_{A} = -55^{\circ}\text{C}) \\ &(I_{C} = 150 \text{ mAdc, } V_{CE} = 10 \text{ Vdc) (Note 1.)} \\ &(I_{C} = 150 \text{ mAdc, } V_{CE} = 1.0 \text{ Vdc) (Note 1.)} \\ &(I_{C} = 500 \text{ mAdc, } V_{CE} = 10 \text{ Vdc) (Note 1.)} \end{aligned} $ | MPS2222A only MPS2222 MPS2222A | hFE | 35 50 75 35 100 50 30 40 | - - - 300 - - | - |
| Collector–Emitter Saturation Voltage (Note 1.) (I _C = 150 mAdc, I _B = 15 mAdc) | MPS2222 MPS2222A | VCE(sat) | - - | 0.4 0.3 | Vdc |
| $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$ | MPS2222 MPS2222A | | - - | 1.6 1.0 | |
| Base–Emitter Saturation Voltage (Note 1.) (I _C = 150 mAdc, I _B = 15 mAdc) | MPS2222 MPS2222A | V _{BE} (sat) | - 0.6 | 1.3 1.2 | Vdc |
| $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$ | MPS2222 MPS2222A | | - - | 2.6 2.0 | |

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

| Characteristic | | | Symbol | Min | Max | Unit |
|--|---|----------------------|-------------------|-------------|-------------|--------------------|
| SMALL-SIGNAL CHARACTERISTIC | CS | | • | | | 1 |
| Current–Gain – Bandwidth Product (Note (I _C = 20 mAdc, V _{CE} = 20 Vdc, f = 100 | , | MPS2222 MPS2222A | fΤ | 250 300 | _ _ | MHz |
| Output Capacitance (V _{CB} = 10 Vdc, I _E = | 0, f = 1.0 MHz) | | C _{obo} | - | 8.0 | pF |
| Input Capacitance (V _{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz) | | MPS2222 MPS2222A | C _{ibo} | - - | 30 25 | pF |
| Input Impedance (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 (I _C = 10 mAdc, V _{CE} = 10 Vdc, f = 1.0 I | | MPS2222A MPS2222A | h _{ie} | 2.0 0.25 | 8.0 1.25 | kΩ |
| Voltage Feedback Ratio (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 (I _C = 10 mAdc, V _{CE} = 10 Vdc, f = 1.0 kg.) | | MPS2222A MPS2222A | h _{re} | - - | 8.0 4.0 | X 10 ⁻⁴ |
| Small–Signal Current Gain (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 (I _C = 10 mAdc, V _{CE} = 10 Vdc, f = 1.0 kg.) | | MPS2222A MPS2222A | h _{fe} | 50 75 | 300 375 | - |
| Output Admittance (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 (I _C = 10 mAdc, V _{CE} = 10 Vdc, f = 1.0 H | | MPS2222A MPS2222A | h _{oe} | 5.0 25 | 35 200 | μmhos |
| Collector Base Time Constant (IE = 20 mAdc, V _{CB} = 20 Vdc, f = 31.8 | MHz) | MPS2222A | rb′C _C | - | 150 | ps |
| Noise Figure $(I_{C}=100~\mu Adc,~V_{CE}=10~Vdc,~R_{S}=1.0~k\Omega,~f=1.0~kHz)$ MPS2222A | | NF | - | 4.0 | dB | |
| SWITCHING CHARACTERISTICS | MPS2222A only | | | | | |
| Delay Time | $(V_{CC} = 30 \text{ Vdc}, V_{BE(off)} = -0.5 \text{ Vdc},$ $I_{C} = 150 \text{ mAdc}, I_{B1} = 15 \text{ mAdc}) \text{ (Figure 1)}$ | | td | | 10 | ns |
| Rise Time | | | t _r | - | 25 | ns |
| Storage Time | $(V_{CC} = 30 \text{ Vdc}, I_{C} = 150 \text{ mAdc}, I_{B1} = I_{B2} = 15 \text{ mAdc})$ (Figure 2) | | t _S | - | 225 | ns |
| Fall Time | | | t _f | | 60 | ns |

^{2.} f_T is defined as the frequency at which $|h_{\mbox{\scriptsize fe}}|$ extrapolates to unity.

SWITCHING TIME EQUIVALENT TEST CIRCUITS

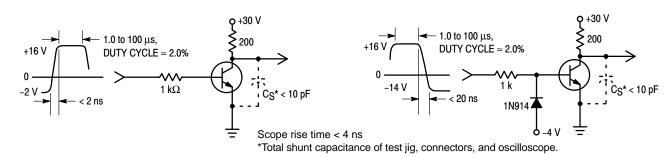


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

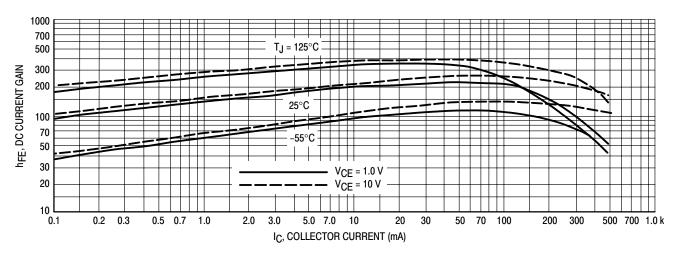


Figure 3. DC Current Gain

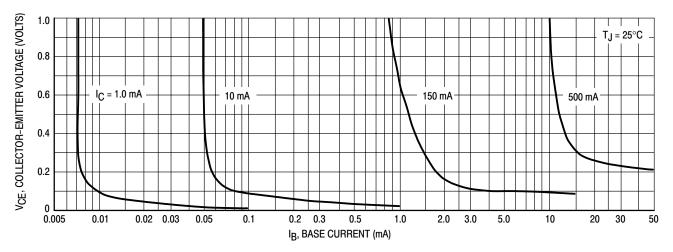


Figure 4. Collector Saturation Region

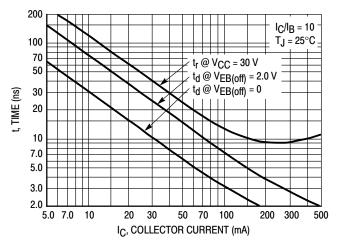


Figure 5. Turn-On Time

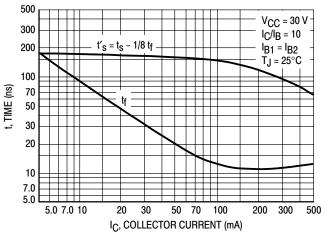


Figure 6. Turn-Off Time

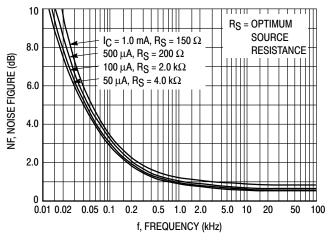


Figure 7. Frequency Effects

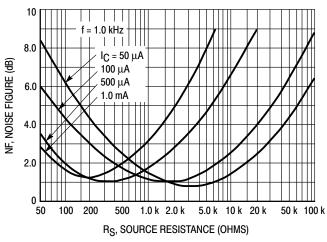


Figure 8. Source Resistance Effects

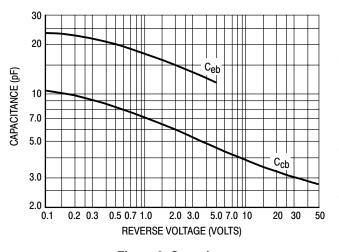


Figure 9. Capacitances

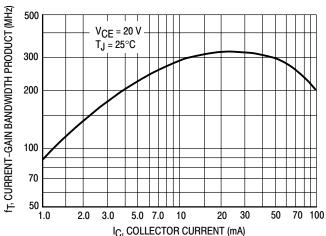
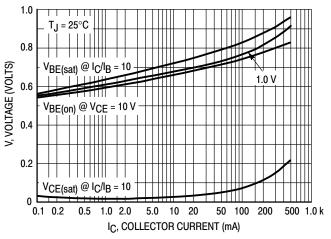


Figure 10. Current-Gain Bandwidth Product





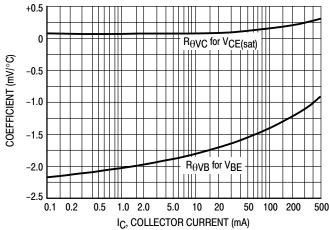
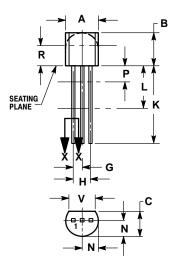


Figure 12. Temperature Coefficients

PACKAGE DIMENSIONS

TO-92 **TO-226AA** CASE 29-11

ISSUE AL





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | INC | INCHES | | IETERS |
|-----|-------|--------|-------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.175 | 0.205 | 4.45 | 5.20 |
| В | 0.170 | 0.210 | 4.32 | 5.33 |
| С | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.021 | 0.407 | 0.533 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| Н | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | | 12.70 | |
| L | 0.250 | | 6.35 | |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| Р | | 0.100 | | 2.54 |
| R | 0.115 | | 2.93 | |
| V | 0 135 | | 3 43 | |

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 14:
PIN 1. EMITTER
2. COLLECTOR
3. BASE

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